

<b>SANYO</b>	No.3712	2SC4547
	NPN Planar Silicon Darlington Transistor Driver Applications	

**Applications**

- Suitable for use in switching of L load (motor drivers, printer hammer drivers, relay drivers).

**Features**

- High DC current gain.
- Large current capacity and wide ASO.
- Contains zener diode of  $95 \pm 10V$  between collector and base.
- Uniformity in collector-to-base breakdown voltage due to adoption of accurate impurity-diffusion process.
- High inductive load handling capability.

**Absolute Maximum Ratings at  $T_a = 25^\circ C$**

			unit
Collector-to-Base Voltage	$V_{CBO}$	※85	V
Collector-to-Emitter Voltage	$V_{CEO}$	※85	V
Emitter-to-Base Voltage	$V_{EBO}$	6	V
Collector Current	$I_C$	3	A
Peak Collector Current	$i_{cp}$	5	A
Base Current	$I_B$	0.5	A
Collector Dissipation	$P_C$	1.75	W
		30	W
Junction Temperature	$T_j$	150	$^\circ C$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ C$

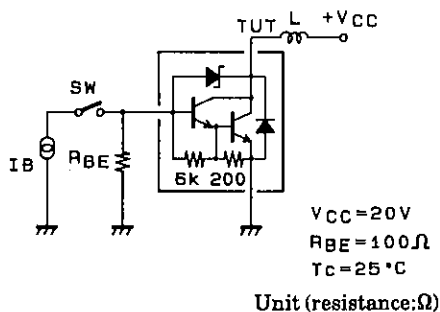
$T_c = 25^\circ C$

※ : With Zener diode ( $95 \pm 10V$ ).

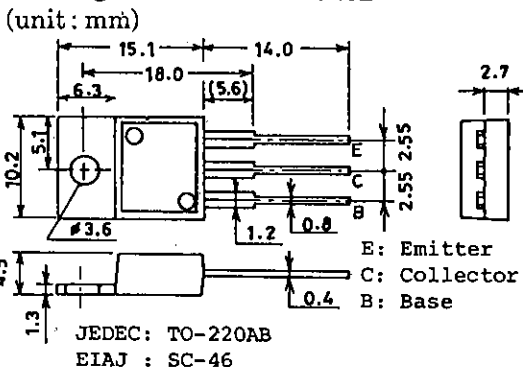
**Electrical Characteristics at  $T_a = 25^\circ C$**

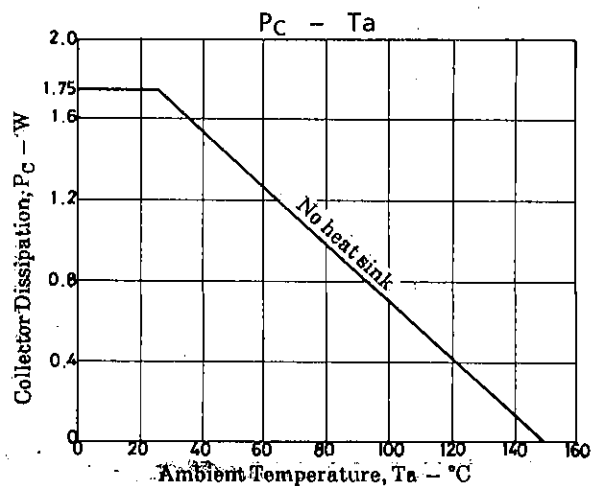
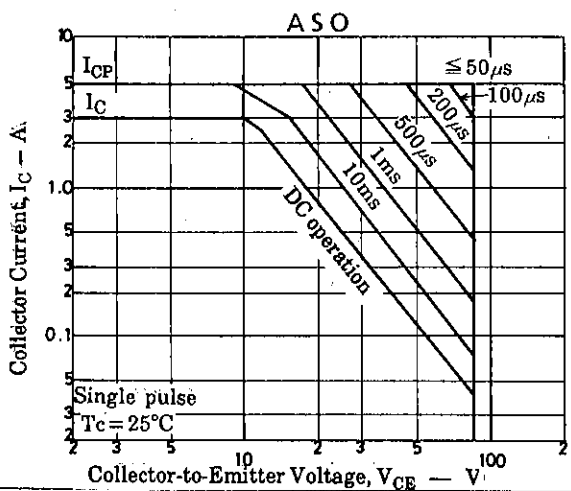
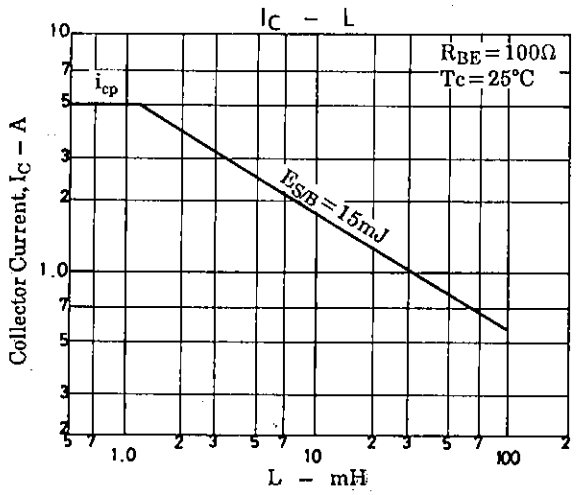
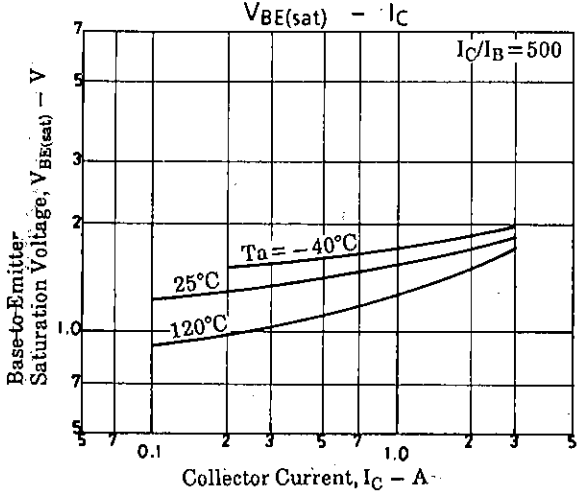
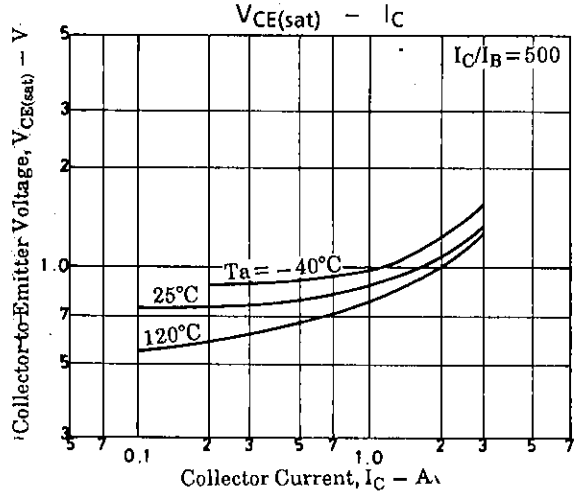
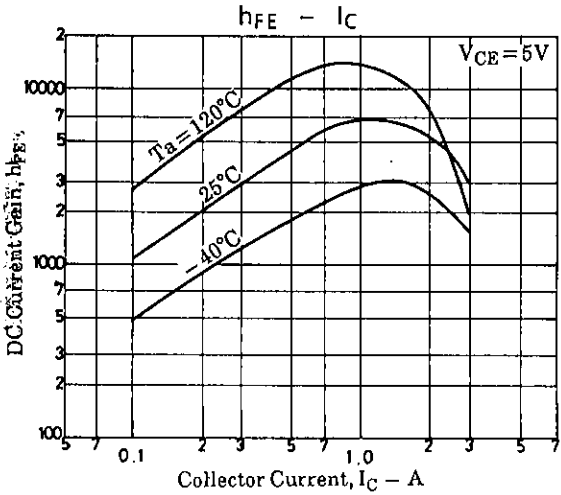
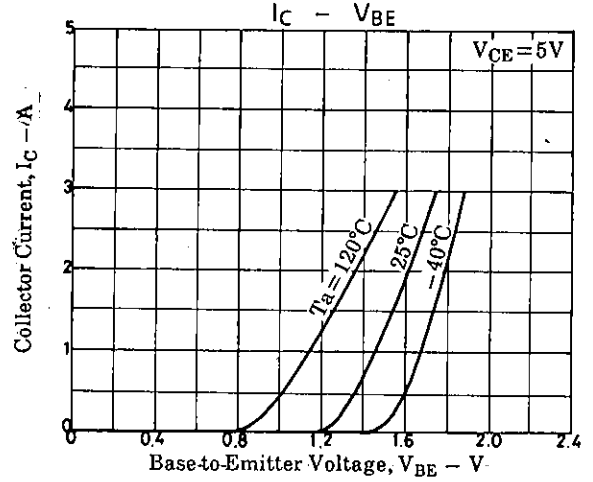
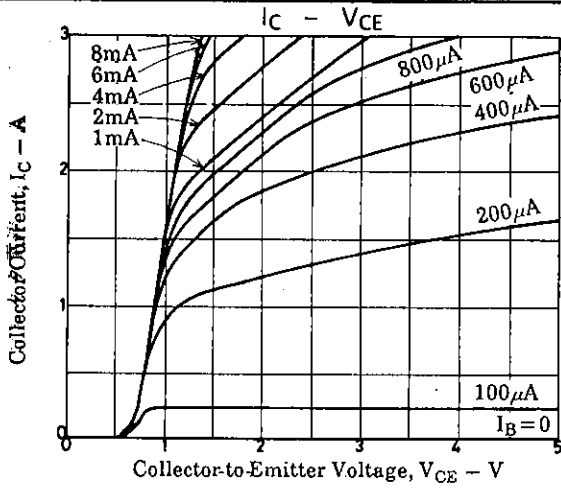
			min	typ	max	unit
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = 70V, I_E = 0$			10	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = 5V, I_C = 0$			3	mA
DC Current Gain	$h_{FE}$	$V_{CE} = 3V, I_C = 1.5A$	2000	6000		
Gain-Bandwidth Product	$f_T$	$V_{CE} = 5V, I_C = 1.5A$		50		MHz
C-E Saturation Voltage	$V_{CE(sat)}$	$I_C = 1.5A, I_B = 3mA$		0.9	1.5	V
B-E Saturation Voltage	$V_{BE(sat)}$	$I_C = 1.5A, I_B = 3mA$			2.0	V
C-B Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 0.1mA, I_E = 0$	85	95	105	V
C-E Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1mA, R_{BE} = \infty$	85	95	105	V
Inductive Load Voltage	$Es/b$	$L = 100mH, R_{BE} = 100\Omega$	15			mJ

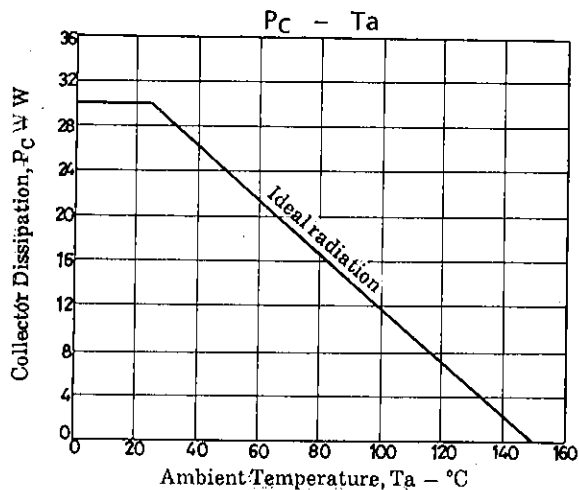
**Es/b Test Circuit**



**Package Dimensions 2010B**







- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
  - ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use;
  - ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.